查询CGY888C供应

CGY888C

34 dB, 870 MHz GaAs push-pull forward amplifierRev. 4 — 28 September 2010Proce

Product data sheet

1. **Product profile**

1.1 General description

Hybrid amplifier module in a SOT115J package, operating at a supply voltage of 24 V (DC), employing Hetero junction Field Effect Transistor (HFET) GaAs MMIC.

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features and benefits

- High gain
- Excellent linearity
- Superior levels of ESD protection
- Extremely low noise
- Excellent return loss properties
- Gain compensation over temperature
- Rugged construction
- Unconditionally stable
- Thermally optimized design
- Compliant with Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)
- Integrated ring wave surge protection

1.3 Applications

CATV systems operating in the 40 MHz to 870 MHz frequency range





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1.4 Quick reference data

Table 1. Quick reference data

Bandwidth to 870 MHz; $V_B = 24$ V (DC); $T_{mb} = 35$ °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G _p	power gain	f = 45 MHz	-	34	-	dB
		f = 870 MHz	34.5	-	36.5	dB
I _{tot}	total current		<u>[1]</u> 260	280	300	mA

[1] Direct Current (DC).

2. Pinning information

Table 2.	Pinning	
Pin	Description	Simplified outline Graphic symbol
1	input	
2, 3	common	1 3 5 7 9
5	+V _B	
7, 8	common	
9	output	sym095

3. Ordering information

Table 3. Orde	ering inform	nation	
Type number	Package		
	Name	Description	Version
CGY888C	-	rectangular single-ended package; aluminium flange; 2 vertical mounting holes; $2 \times 6-32$ UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads	SOT115J

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
VB	supply voltage		-	30	V
V _{i(RF)}	RF input voltage	single tone	-	70	dBmV
V _{ESD}	electrostatic discharge voltage	Human Body Model (HBM); According JEDEC standard 22-A114E	-	2000	V
		Biased; According IEC61000-4-2	-	2000	V
T _{stg}	storage temperature		-40	+100	°C
T _{mb}	mounting base temperature		-20	+100	°C

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5. Characteristics

Table 5. Characteristics

Bandwidth to 870 MHz; $V_B = 24 V (DC)$; $T_{mb} = 35 \ ^{\circ}C$; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Gp	power gain	f = 45 MHz		-	34	-	dB
		f = 870 MHz		34.5	-	36.5	dB
SL _{sl}	slope straight line	f = 45 MHz to 870 MHz	[1]	-	1.5	-	dB
FL	flatness of frequency response	f = 45 MHz to 870 MHz	[2]	-	0.25	-	dB
СТВ	composite triple beat	112 NTSC channels	[3]	-	-	-65	dBc
		98 PAL channels	[4]	-	-68	-	dBc
CSO	composite second-order distortion	112 NTSC channels	[3]	-	-	-63	dBc
		98 PAL channels	[4]	-	-66	-	dBc
Xmod	cross modulation	112 NTSC channels	[3]	-	-72	-	dB
RL _{in}	input return loss	f = 45 MHz to 320 MHz		20	-	-	dB
		f = 320 MHz to 870 MHz		18	-	-	dB
RL _{out}	output return loss	f = 45 MHz to 320 MHz		20	-	-	dB
		f = 320 MHz to 870 MHz		17	-	-	dB
NF	noise figure	f = 50 MHz		-	3.5	4.0	dB
		f = 870 MHz		-	4.0	5.0	dB
I _{tot}	total current		[5]	260	280	300	mA

[1] G_p at 870 MHz minus G_p at 45 MHz.

[2] Flatness straight line (peak to valley).

[3] f = 55.25 MHz to 745.25 MHz; V_o = 44 dBmV, flat output level.

[4] f = 49.75 MHz to 847.25 MHz; V_o = 44 dBmV, flat output level.

[5] Direct Current (DC).

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6. Package outline

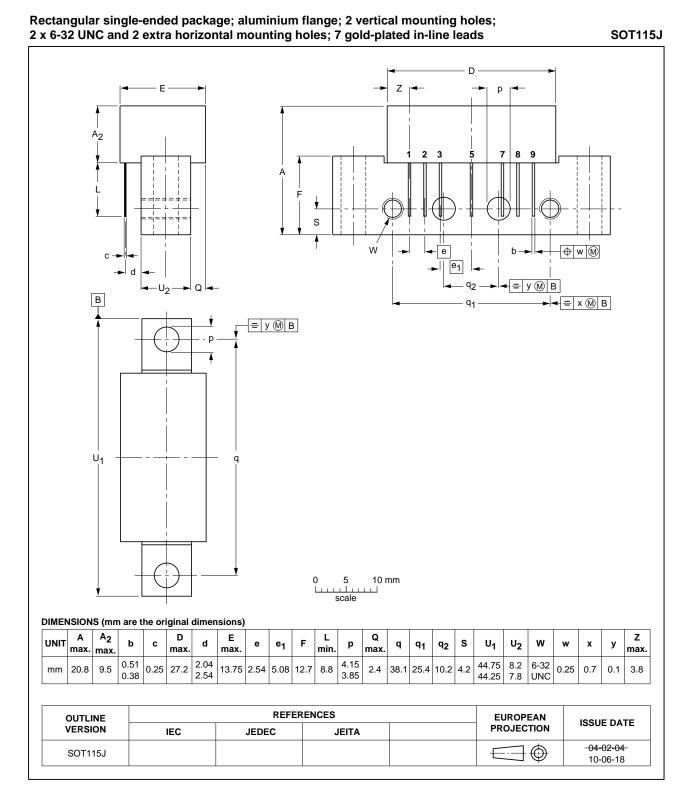


Fig 1. Package outline SOT115J

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7. Abbreviations

Acronym	Description
	•
CATV	Community Antenna TeleVision
DC	Direct Current
GaAs	Gallium-Arsenide
MMIC	Monolithic Microwave Integrated Circuit
NTSC	National Television Standard Committee
PAL	Phase Alternating Line
RF	Radio Frequency
UNC	UNified Coarse

8. Revision history

Table 7. Revis	ion history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
CGY888C v.4	20100928	Product data sheet	-	CGY888C v.3
Modifications:	 Package out 	line drawings have been update	ed to the latest version.	
	 Legal texts h 	ave been updated.		
CGY888C v.3	20091014	Product data sheet	-	CGY888C v.2
CGY888C v.2	20090921	Product data sheet	-	CGY888C v.1
CGY888C v.1	20080619	Product data sheet	-	-

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9. Legal information

9.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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Date of release: 28 September 2010 Document identifier: CGY888C